

ESH2PB, ESH2PC & ESH2PD

Vishay General Semiconductor

HALOGEN

High Current Density Surface Mount Ultrafast Rectifiers



DO-220AA (SMP)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2.0 A				
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V_F at $I_F = 2 A$	0.75 V				
T _J max.	175 °C				

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of ac-to-ac and dc-to-dc converters in high temperature conditions for both consumer and automotive applications.

FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- · Glass passivated chip junction
- Ultrafast recovery times for high frequency
- · Low forward voltage drop, low power loss
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT
Device marking code		P2B	P2C	P2D	
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	2.0		Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50			А
Operating junction and storage temperature range	T_J , T_{STG}	- 55 to + 175			°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum instantaneous forward voltage (1)	I _F = 2 A	T _J = 25 °C T _J = 125 °C	V _F	0.90 0.75	0.98 0.82	V
Maximum reverse current (2)	Rated V _R	T _J = 25 °C T _J = 125 °C	I _R	0.2 12.6	1.0 25	μΑ
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	-	25	ns

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Typical reverse recovery time	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A}/\mu\text{s},$	T _J = 25 °C T _J = 100 °C	t _{rr}	-	25 35	ns
Typical stored charge	$I_{rr} = 10 \% I_{RM}$	T _J = 100 °C	Q _{rr}	-	10 15	nC
Typical junction capacitance	4.0 V, 1 MHz		CJ	-	25	pF

Notes:

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{^{(2)}}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH2PB	ESH2PC	ESH2PD	UNIT
Typical thermal resistance ⁽¹⁾	$egin{array}{l} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$		80 15 22		°C/W

Note

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 mm x 6.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel		
ESH2PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel		
ESH2PBHM3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel		

Note:

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

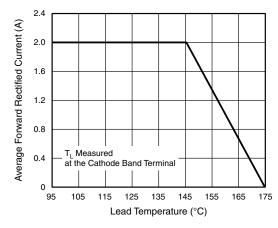


Figure 1. Forward Current Derating Curve

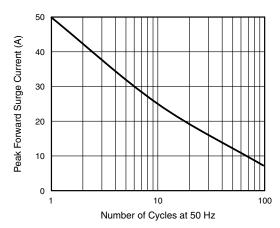


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

⁽¹⁾ Automotive grade

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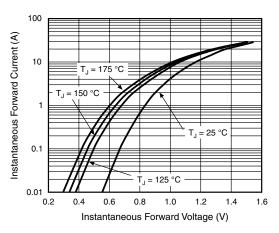


Figure 3. Typical Instantaneous Forward Characteristics

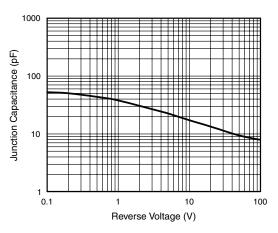


Figure 5. Typical Junction Capacitance

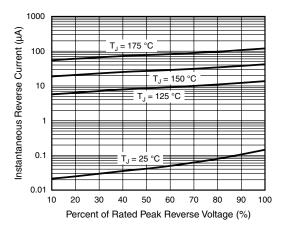


Figure 4. Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP) 0.012 (0.30) REF. Cathode Band 0.086 (2.18) 0.053 (1.35) 0.036 (0.91) 0.074 (1.88) 0.041 (1.05) 0.024 (0.61) 0.142 (3.61) 0.103 (2.60) 0.032 (0.80) 0.126 (3.19) 0.087 (2.20) 0.016 (0.40) 0.158 (4.00) 0.146 (3.70) 0.025 0.030 (0.635) (0.762) 0.105 0.013 (0.35) 0.004 (0.10) 0.045 (1.15) 0.033 (0.85) 0.100 (2.54) 0.050 (1.27) 0.012 (0.30) 0.018 (0.45) 0.000 (0.00) 0.006 (0.15)

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